

DMN4035L-13 Datasheet

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DiGi Electronics Part Number	DMN4035L-13-DG
Manufacturer	Diodes Incorporated
Ianufacturer Product Number	DMN4035L-13
Description	MOSFET N-CH 40V 4.6A SOT23
Detailed Description	N-Channel 40 V 4.6A (Ta) 720mW Surface Mount SO T-23-3

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
DMN4035L-13	Diodes Incorporated
Series:	Product Status:
-	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
40 V	4.6A (Ta)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
4.5V, 10V	42mOhm @ 4.3A, 10V
Vgs(th) (Max) @ ld:	Gate Charge (Qg) (Max) @ Vgs:
3V @ 250µA	12.5 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±20V	574 pF @ 20 V
FET Feature:	Power Dissipation (Max):
-	720mW
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Supplier Device Package:	Package / Case:
SOT-23-3	TO-236-3, SC-59, SOT-23-3
Base Product Number:	
DMN4035	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0095	





DMN4035L

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max
	42mΩ @ V _{GS} = 10V	4.6A
40V	52mΩ @ V _{GS} = 4.5V	4.1A

N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Low Input Capacitance

Mechanical Data

Case: SOT23

- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
 - https://www.diodes.com/quality/product-definitions/

UL Flammability Classification Rating 94V-0

Moisture Sensitivity: Level 1 per J-STD-020

Solderable per MIL-STD-202, Method 208 3

Terminals Connections: See Diagram Below

An Automotive-Compliant Part is Available Under Separate Datasheet (DMN4035LQ)

Case Material: Molded Plastic, "Green" Molding Compound.

Terminals: Finish — Matte Tin Annealed over Copper Leadframe.

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

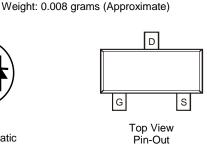
- Battery Charging
- Power Management Functions
- DC-DC Converters
- Portable Power Adaptors

SOT23





D G S



Internal Schematic

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN4035L-7	SOT23	3000/Tape & Reel
DMN4035L-13	SOT23	10000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:

Dat	te Code Ke	€Y		[35L]	Y Y	M = Date 0 or $\overline{Y} = Ye$	uct Type Ma Code Markii ar (ex: G = 2 (ex: 9 = Sep	ng 2019)			
	Year	2019	20	20	2021	2022	20	23	2024	2025	20)26	2027
	Code	G	ł	4		J		<	L	М		N	0
	Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
	Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage		VDSS	40	V	
Gate-Source Voltage		V _{GSS}	±20	V	
Continuous Drain Current (Note 6) V_{GS} = 10V	T _A = +25°C T _A = +70°C	ID	4.6 3.7	А	
Maximum Body Diode Forward Current (Note 6)			ls	1.5	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	Ідм	25	А		
Pulsed Source Current (10µs Pulse, Duty Cycle = 1	%)		lsм	25	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Power Dissipation (Note 5)		PD	0.72	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	171	°C/W
Power Dissipation (Note 6)	·	PD	1.4	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	93	°C/W
Operating and Storage Temperature Range	·	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

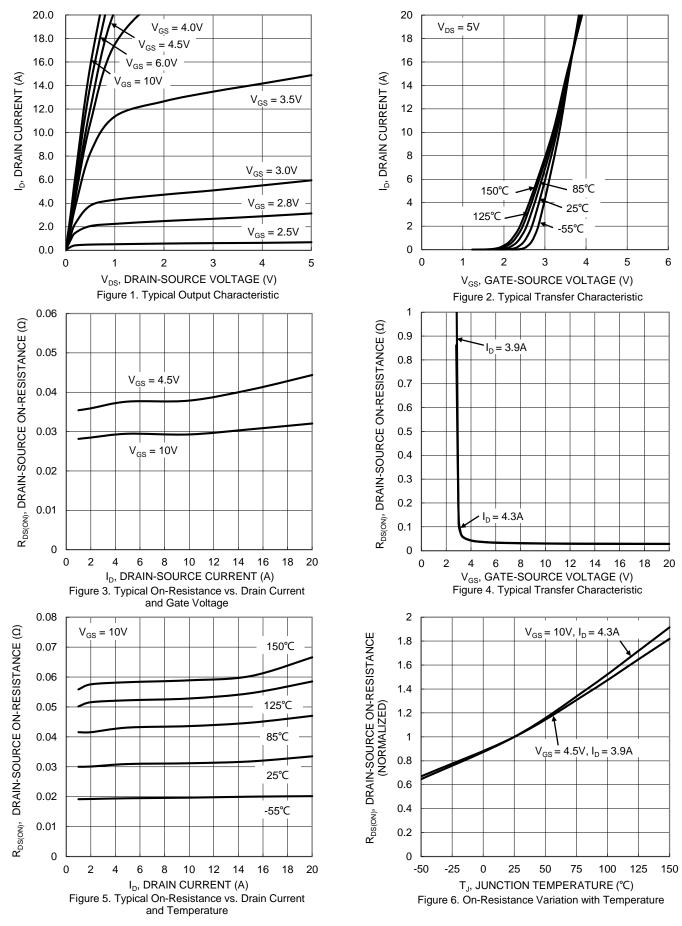
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	40	_		V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	$V_{DS} = 40V, V_{GS} = 0V$
Gate-Source Leakage	lgss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)			•	•	•	·
Gate Threshold Voltage	V _{GS(TH)}	1	—	3	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Static Drain-Source On-Resistance	Descent	_	30	42	mΩ	Vgs = 10V, ID = 4.3A
Static Drain-Source On-Resistance	RDS(ON)	_	40	52	11152	VGS = 4.5V, ID = 3.9A
Diode Forward Voltage	V _{SD}		0.7	1.1	V	V _{GS} = 0V, I _S = 1.25A
DYNAMIC CHARACTERISTICS (Note 8)	•					-
Input Capacitance	Ciss	_	574	_		$V_{DS} = 20V, V_{GS} = 0V,$ f = 1MHz
Output Capacitance	Coss	_	87.8	_	pF	
Reverse Transfer Capacitance	Crss	_	38.7	_		
Gate Resistance	Rg	_	1.6		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	5.9			
Total Gate Charge (V _{GS} = 10V)	Qg		12.5		nC	
Gate-Source Charge	Q _{gs}		1.7		nc	$V_{DS} = 20V, I_D = 3.9A$
Gate-Drain Charge	Q _{gd}		2.2			
Turn-On Delay Time	tD(ON)		3.1			
Turn-On Rise Time	t _R		2.6	_		$V_{DD} = 20V, V_{GS} = 10V,$
Turn-Off Delay Time	t _{D(OFF)}		15		ns	$R_L = 20\Omega, R_G = 6\Omega$
Turn-Off Fall Time	tF	_	5.5	_	1	
Reverse Recovery Time	trr	_	6.5	_	ns	
Reverse Recovery Charge	Q _{RR}	_	1.2		nC	IF = 3.9A, di/dt = 500A/μs

Notes:

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to product testing.

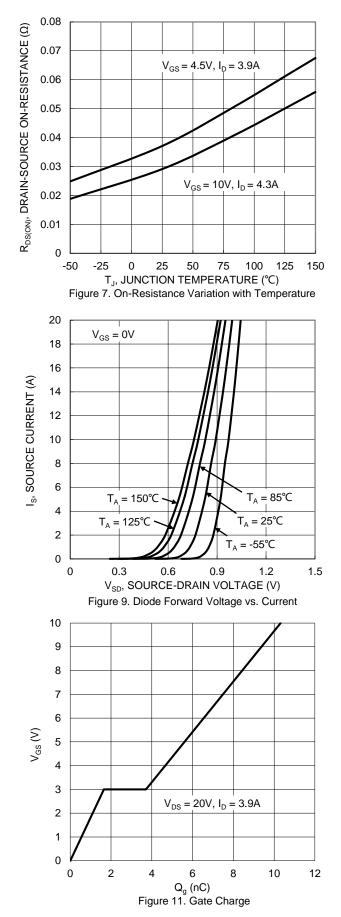


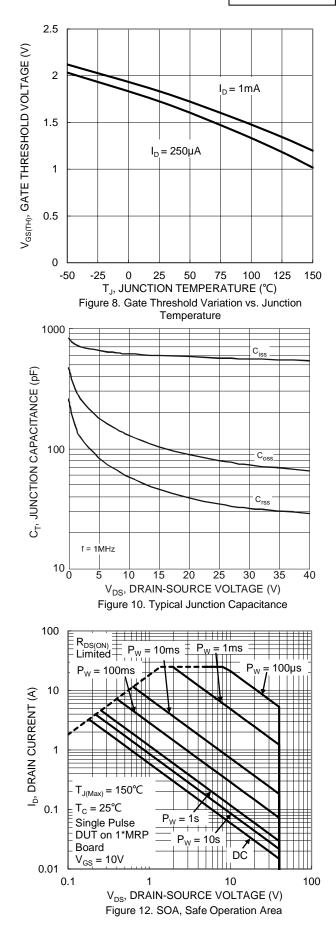
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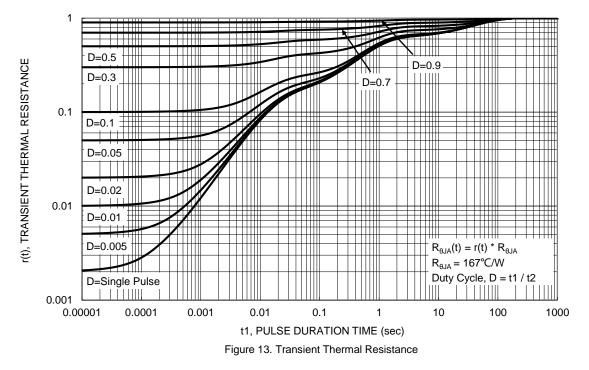
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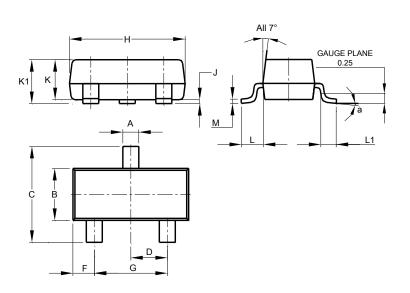
SOT23



DMN4035L

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

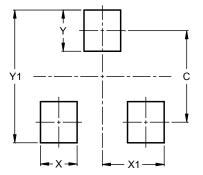


	SOT23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	0°	8°						
All	Dimens	ions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)			
С	2.0			
Х	0.8			
X1	1.35			
Y	0.9			
Y1	2.9			



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